



#### 20V PNP LOW SATURATION TRANSISTOR IN DFN2020

#### **Features and Benefits**

- $BV_{CEO} > -20V$
- I<sub>C</sub> = -3.5A Continuous Collector Current
- Low Saturation Voltage (-220mV max @ -1A)
- $R_{sat} = 64 \text{ m}\Omega$  for a low equivalent on-resistance
- hFE specified up to -6A for high current gain hold up
- Low-profile 0.6mm package for thin applications
- R<sub>θJA</sub> efficient, 60% lower than SOT23
- 4mm<sup>2</sup> footprint, 50% smaller than SOT23
- Totally Lead-Free & Fully RoHS compliant (Notes 2 & 3)
- Halogen and Antimony Free. "Green" Device (Note 2)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

### **Mechanical Data**

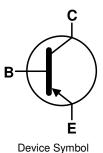
- Package: U-DFN2020-3 (Type B)
- Package Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu, Solderable per MIL-STD-202, Method 208 (e4)
- Weight: 0.01 grams (Approximate)

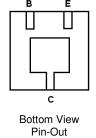
### **Applications**

- MOSFET gate driving
- DC-DC converters
- Charging circuits
- Power switches
- Motor control









**Ordering Information** (Note 4)

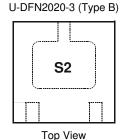
Top View

Ī	Product	Marking	Reel Size (Inches)	Tape Width (mm)	Quantity per Reel
	ZXTP718MATA	S2	7	8	3000
	ZXTP718MATC	S2	13	8	10000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + CI) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

## **Marking Information**



S2 = Product Type Marking code



# Absolute Maximum Ratings @TA = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit	
Collector-Base Voltage		$V_{CBO}$	-25		
Collector-Emitter Voltage		V <sub>CEO</sub>	-20	V	
Emitter-Base Voltage		V <sub>EBO</sub>	-7		
Peak Pulse Current		I <sub>CM</sub>	-6		
Continuous Collector Current	(Note 5)	Ic -	-3.5 -4.0	Α	
Base Current	(Note 6)	I <sub>B</sub>	- <del>1</del> -4.0		

# $\begin{tabular}{ll} \textbf{Thermal Characteristics} @ T_A = \underline{25^{\circ}C \text{ unless otherwise specified}} \\ \end{tabular}$

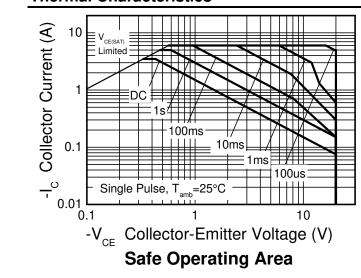
Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)	9	1.5 12		
Linear Derating Factor	(Note 6)	P <sub>D</sub>	2.45 19.6	mW/°C	
Thermal Resistance, Junction to Ambient	(Note 5)	В	83		
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	51	°C/W	
Thermal Resistance, Junction to Lead	(Note 7)	$R_{ heta JL}$	16.8		
Operating and Storage Temperature Range	$T_{J_1}T_{STG}$	-55 to +150	°C		

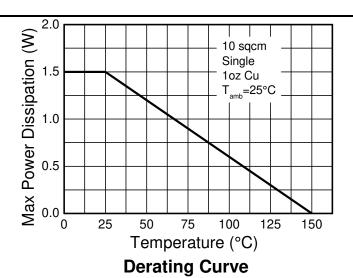
Notes:

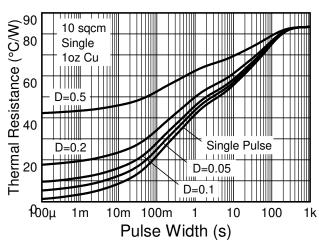
 <sup>5.</sup> For a device surface mounted on 31mm x 31mm (10cm²) FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition. The entire exposed collector pad is attached to the heatsink.
 6. Same as note (3), except the device is measured at t ≤ 5 sec.
 7. For a single device, thermal resistance is from junction to solder-point (at the end of the drain lead).

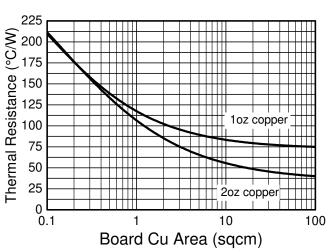


### **Thermal Characteristics**



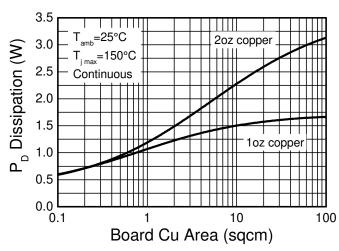






**Transient Thermal Impedance** 

**Thermal Resistance v Board Area** 



Power Dissipation v Board Area



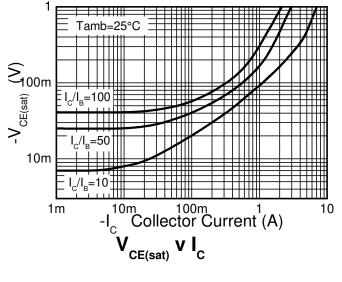
# Electrical Characteristics @TA = 25°C unless otherwise specified

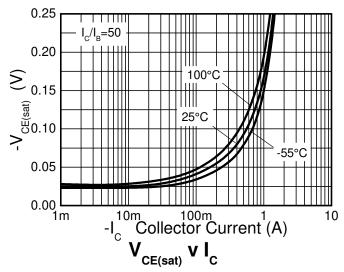
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_CBO$	-25	-35	-	٧	$I_C = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 8)	$BV_CEO$	-20	-25	-	٧	$I_C = -10 \text{ mA}$
Emitter-Base Breakdown Voltage	$BV_{EBO}$	-7	-8.5	-	V	$I_E = -100 \mu A$
Collector Cutoff Current	I <sub>CBO</sub>	-	-	-100	nA	V <sub>CB</sub> = -20V
Emitter Cutoff Current	I <sub>EBO</sub>	-	-	-100	□nA	$V_{EB} = -6V$
Collector Emitter Cutoff Current	I <sub>CES</sub>	-	-	-100	nA	V <sub>CES</sub> = -16V
Static Forward Current Transfer Ratio (Note 8)	h <sub>FE</sub>	300 300 150 15	475 450 230 30		-	$\begin{split} I_C &= \text{-}10\text{mA}, \ V_{CE} = \text{-}2V \\ I_C &= \text{-}100\text{mA}, \ V_{CE} = \text{-}2V \\ I_C &= \text{-}2A, \ V_{CE} = \text{-}2V \\ I_C &= \text{-}6A, \ V_{CE} = \text{-}2V \end{split}$
Collector-Emitter Saturation Voltage (Note 8)	V <sub>CE(sat)</sub>		-19 -170 -190 -240 -225	-30 -220 -250 -350 -300	mV	$I_C = -0.1A$ , $I_B = -10mA$ $I_C = -1A$ , $I_B = -20mA$ $I_C = -1.5A$ , $I_B = -50mA$ $I_C = -2.5A$ , $I_B = -150mA$ $I_C = -3.5A$ , $I_B = -350mA$
Base-Emitter Turn-On Voltage (Note 8)	V <sub>BE(on)</sub>	-	-0.87	-0.95	V	I <sub>C</sub> = -3.5A, V <sub>CE</sub> = -2V
Base-Emitter Saturation Voltage (Note 8)	V <sub>BE(sat)</sub>	-	-1.01	-1.120	V	$I_C = -3.5A$ , $I_B = -350mA$
Output Capacitance	$C_{ m obo}$	-	21	30	pF	V <sub>CB</sub> =-10V. f = 1MHz
Transition Frequency	f <sub>T</sub>	150	180	-	MHz	V <sub>CE</sub> = -10V, I <sub>C</sub> = -50mA, f = 100MHz
Turn-On Time	t <sub>on</sub>	-	40	-	ns	$V_{CC} = -10V, I_{C} = -1A$
Turn-Off Time	t <sub>off</sub>	-	670	-	ns	$I_{B1} = -I_{B2} = -10mA$

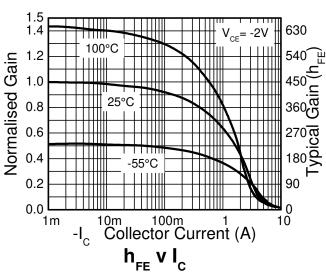
Notes: 8. Measured under pulsed conditions. Pulse width  $\leq$  300  $\mu$ s. Duty cycle  $\leq$  2%.

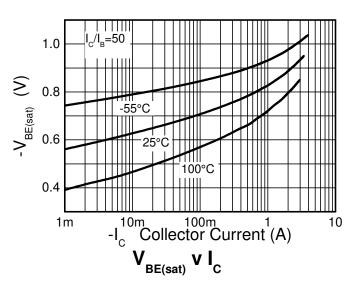


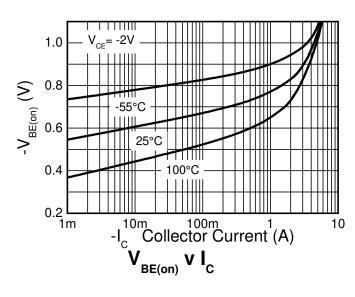
## **Typical Electrical Characteristics**









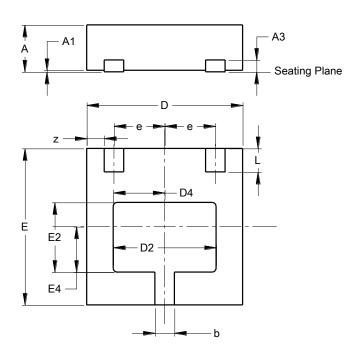




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### U-DFN2020-3 (Type B)

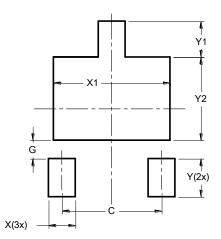


U-DFN2020-3 (Type B)						
Dim	Min	Max	Тур			
Α	0.57	0.63	0.60			
A1	0.00	0.05	0.02			
А3			0.152			
b	0.20	0.30	0.25			
D	1.950	2.075	2.00			
D2	1.22	1.42	1.32			
D4	0.56	0.76	0.66			
Ε	1.950	2.075	2.00			
E2	0.79	0.99	0.89			
E4	0.48	0.68	0.58			
е			0.65			
L	0.25	0.35	0.30			
Z			0.225			
All Dimensions in mm						

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### U-DFN2020-3 (Type B)



Dimensions	value		
Dimonorono	(in mm)		
С	1.300		
G	0.240		
X	0.350		
X1	1.520		
Υ	0.500		
Y1	0.470		
Y2	1.090		



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